



PAM8007

FILTERLESS 3W CLASS-D STEREO AUDIO AMPLIFIER with DC VOLUME CONTROL and HEADPHONE OUTPUT

SSOP24

Pin Assignments

Description

The PAM8007 is a 3W, Class-D audio amplifier with headphone amplifier. Advanced 64-Step DC volume control minimizes external components and allows speaker volume control and headphone volume control. It offers low THD+N, to produce high-quality sound reproduction. The new filterless architecture allows the device to drive the speaker directly, without low-pass output filters which will save 30% system cost and 75% PCB area.

With the same numbers of external components, the efficiency of the PAM8007 is much better than class-AB cousins. It can extend the battery life thus be ideal for portable applications.

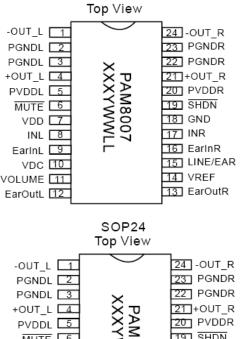
The PAM8007 is available in a SSOP-24 and SOP-24 package.

Features

- 3W Output at 10% THD with a 4Ω Load and 5V Power Supply
- Filterless, Low Quiescent Current and Low EMI
- Low THD+N
- 64-Step DC Volume Control
- Headphone Output Function
- Superior Low Noise
- Low Pop Noise
- Efficiency Up to 92%
- Short Circuit Protection
- Thermal Shutdown
- Few External Components to Save the Space and Cost
- Pb-Free Package

Applications

- LCD Monitors / TV Projectors
- Notebook Computers
- Portable Speakers
- Portable DVD Players, Game Machines
- VoIP/Speaker Phones

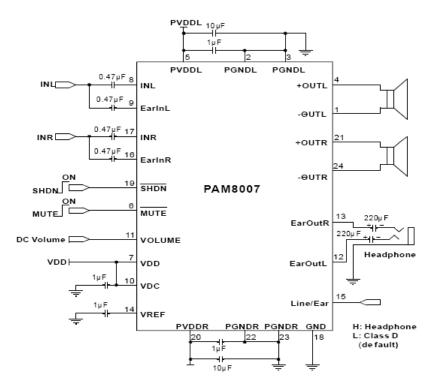


MUTE 6	< 8	19 SHDN
	≥õ	18 GND
INL 🔼		17 INR
EarInL 9	i i	16 EarInR
VDC 10		15 LINE/EAR
VOLUME 11		14 VREF
EarOutL 12		13 EarOutR





Typical Applications Circuit



Pin Descriptions

Pin Number	Pin Name	Function
1	-OUT_L	Left Channel Negative Output
2	PGNDL	Left Channel Power GND
3	PGNDL	Left Channel Power GND
4	+OUT_L	Left Channel Positive Output
5	PVDDL	Left Channel Power Supply
6	MUTE	Mute Control Input (active low)
7	VDD	Analog VDD
8	INL	Left Channel Input
9	EAR INL	Left Earphone Input
10	VDC	Analog Reference for Gain Control Section
11	VOLUME	DC Volume Control to Set the Gain of Class-D
12	EAR OUT L	Left Earphone Output(Non-Inverting)
13	EAR OUT R	Right Earphone Output(Non-Inverting)
14	VREF	Internal Analog Reference, connect a bypass capacitor from VREF to GND
15	LINE/EAR	Line / Earphone Switch. Speaker Output (active low), Earphone Output (active high)
16	EAR LN R	Right Earphone Input
17	INR	Right Channel Input
18	GND	Analog GND
19	SHDN	Shutdown Control Input (active low)
20	PVDDR	Right Channel Power Supply
21	+OUT_R	Right Channel Positive Output
22	PGNDR	Right Channel Power GND
23	PGNDR	Right Channel Power GND
24	-OUT_R	Right Channel Negative Output





Functional Block Diagram VDD PVDD PGND -Headphone EarOutR EarInR VDD/2 +OUT_R INR DRIVER MODULATOR -OUT_R Thermal Protection Attenuation Decoder VDC 5 terface MUTE BIAS AND REFERENCES INTERNAL SHDN 🛉 OSCILLATOR VREF Contro LINE/EAR VOLUME osc Current Protection ٠ MODULATOR +OUT_L DRIVER INL -OUT_L VDD/2-EarInL Headphone EarOutL GND PVDD PGND

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
Supply Voltage	6.0	N
Input Voltage	-0.3 to V _{DD} +0.3	v
Maximum Junction Temperature	150	
Storage Temperature	-65 to +150	°C
Soldering Temperature	300, 5sec	

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Supply Voltage Range	2.5 to 5.5	V
Ambient Operation Temperature Range	-20 to +85	°C
Junction Temperature Range	-20 to +125	°C





Thermal Information

Parameter	Package	Symbol	Max	Unit
Thermal Resistance (Junction to Ambient)	SSOP-24	0	90	°C/W
Thermal Resistance (Sunction to Ambient)	SOP-24	θ _{JA}	79.2	
Thermal Resistance (Junction to Case)	SSOP-24	0	32	C/W
Thermal Resistance (Sunction to Case)	SOP-24	θ _{JC}	27	

Electrical Characteristics (@T_A = +25°C, V_{DD} = 5V, Gain = 24dB, R_L = 8 Ω , unless otherwise specified.)

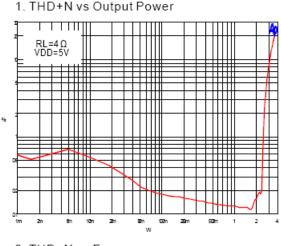
Parameter	Symbol	Test Conditions		Min	Тур	Max	Units	
Class D Stage								
Supply Voltage Range	V _{DD}			2.5		5.5	V	
Quiescent Current	lq	No Load			12	16	mA	
Output Offset Voltage	V _{OS}	No Load			10	50	mV	
Drain-Source On-State Resistance	_		P MOSFET		0.23		Ω	
	R _{DS(ON)}	I _{DS} = 0.5A	N MOSFET		0.17		12	
Output Power	Po	THD+N = 10%	R _L = 8Ω	1.55	1.75		w	
	10	f = 1kHz	R _L = 4Ω	2.85	3.1	3.1 W		
	THD+N	$R_L = 8\Omega, P_O = 1W, f$	= 1KHz		0.12		%	
Total Harmonic Distortion Plus Noise		$R_L = 4\Omega, P_O = 2W, f$	= 1KHz		0.15		70	
Power Supply Ripple Rejection	PSRR	Input AC-GND, f = 1	KHz, V _{PP} = 200mV		63		dB	
Channel Separation	CS	$V_0 = 1V_{RMS}$, f = 1KH	Z		-88		dB	
Oscillator Frequency	fosc			200	250	300	kHz	
Efficiency	n	P _O = 1.75W, f =1 kHz	z, R _L = 8Ω	85	92		%	
Efficiency	η	P _O = 3.0W, f =1 kHz,	R _L = 4Ω	80	88		%	
Noise		Input AC-GND	A-Weighting		65			
NOISE	V _N	Gain = 12dB	No A-Weighting		90		μV	
Signal Noise Ratio	SNR	f = 20 – 20kHz, THD = 1%			84		dB	
Earphone Stage	-							
Output Power	Po	THD+N = 1%, R _L = 32Ω, f = 1kHz			69		mW	
Total Harmonic Distortion Plus Noise	THD+N	$R_L = 32\Omega, P_O = 10mV$	W, f = 1kHz		0.04		%	
Power Supply Ripple Rejection	PSRR	Input AC-GND, f = 1	kHz, V _{PP} = 200mV		73		dB	
Channel Separation	CS	$V_{O} = 1V_{RMS}$, f = 1kHz	Z		95		dB	
Noise	V _N	Input	A-Weighting		19		μV	
		AC-GND	No A-Weighting		25			
Signal Noise Ratio	SNR	f = 20 – 20kHz, THD	= 1%		97		dB	
Control Section	1						1	
Mute Current	I _{MUTE}	V _{MUTE} = 0V			8	12	mA	
Shutdown Current	ISHDN	V _{SHDN} = 0V				20	μA	
SHDN Input High	V _{SH}			1.5			v	
SHDN Input Low	V _{SL}					0.4	v	
MUTE Input High	V _{MH}	мн 1.5		1.5			v	
MUTE Input Low	V _{ML}					0.4	v	
Line/Ear Input High	V _{DH}			2.5			v	
Line/Ear Input Low	V _{DL}					0.4	v	
Over Temperature Protection	OTP				150		°C	
Over Temperature Hysteresis	OTH				30		°C	



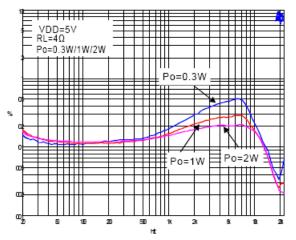


Typical Performance Characteristics (@TA = +25°C, unless otherwise specified.)

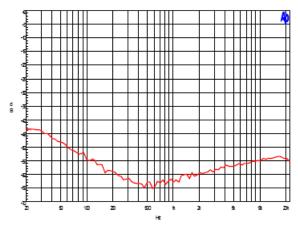
Speaker



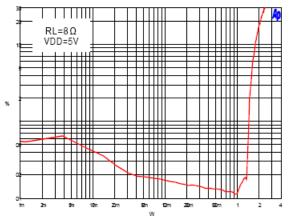
3. THD+N vs Frequency



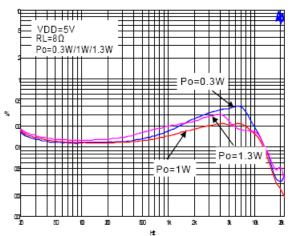
5. PSRR vs Frequency



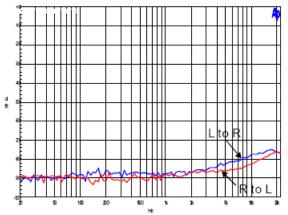
2. THD+N vs Output Power



4. THD+N vs Frequency



6. Crosstalk vs Frequency

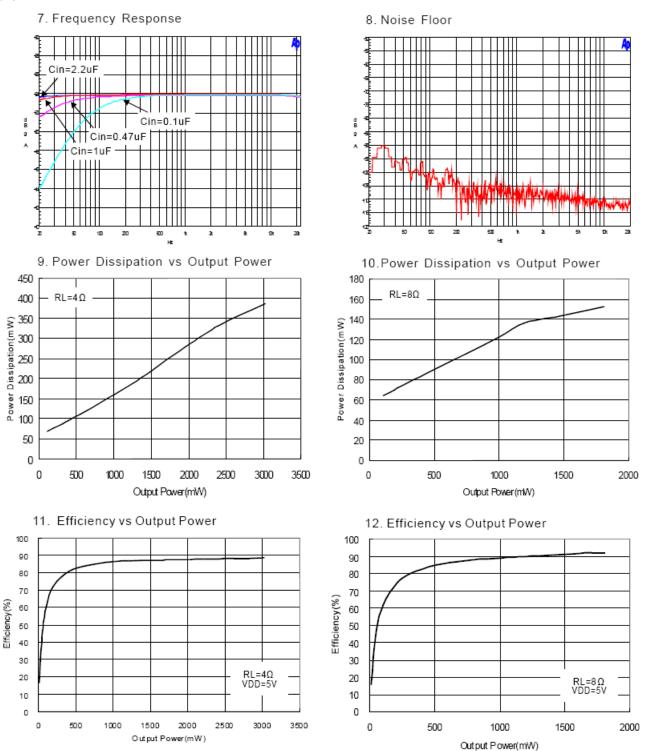






Typical Performance Characteristics (cont.) (@TA = +25°C, unless otherwise specified.)

Speaker

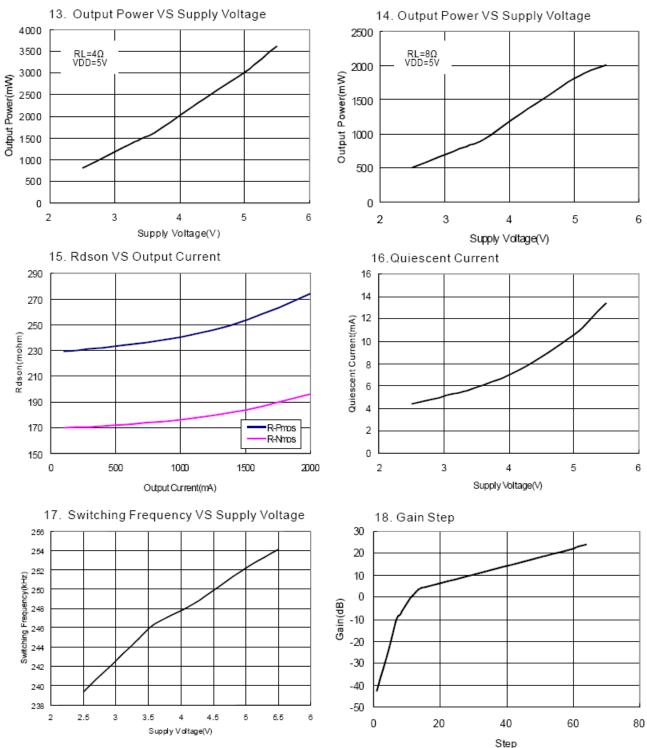






Typical Performance Characteristics (cont.) (@T_A = +25°C, unless otherwise specified.)



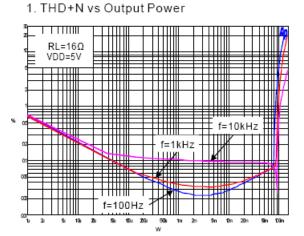




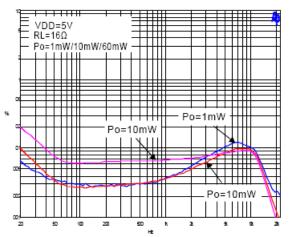


Typical Performance Characteristics (cont.) (@TA = +25°C, unless otherwise specified.)

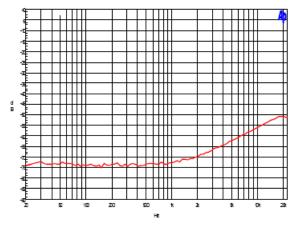
Earphone Output



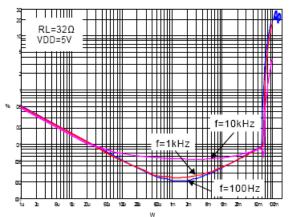
3. THD+N vs Frequency



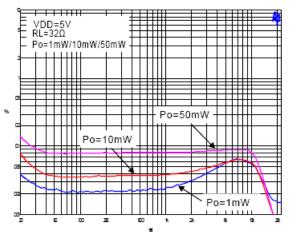
5. PSRR vs Frequency



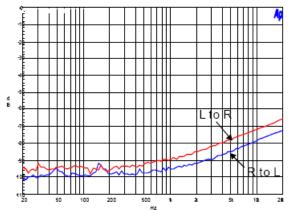
2. THD+N vs Output Power



4. THD+N vs Frequency



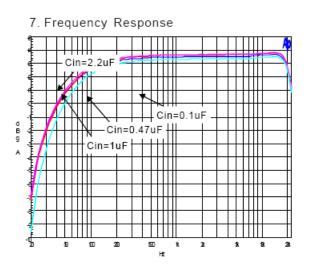
6. Crosstalk vs Frequency

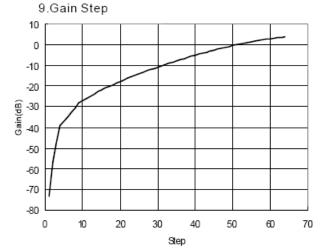


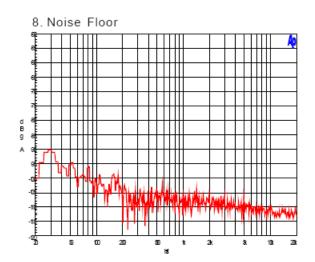




Typical Performance Characteristics (cont.) (@T_A = +25°C, unless otherwise specified.)











Typical Performance Characteristics (cont.) (@T_A = +25°C, unless otherwise specified.)

Table 1. DC Volume Control

STEP	Gain (dB) Class D	Gain (dB) Earphone	STEP	Gain (dB) Class D	Gain (dB) Earphone
1	-80	-80	33	11.6	-9.2
2	-40	-60	34	12.0	-8.6
3	-34	-50	35	12.4	-8.0
4	-28	-40	36	12.8	-7.4
5	-22	-37.7	37	13.2	-6.8
6	-16	-35.4	38	13.6	-6.2
7	-10	-33.1	39	14.0	-5.7
8	-7.5	-30.8	40	14.4	-5.2
9	-5	-28.5	41	14.8	-4.7
10	-2.5	-27.5	42	15.2	-4.2
11	0	-26.4	43	15.6	-3.7
12	1.5	-25.3	44	16.0	-3.2
13	3.0	-24.2	45	16.4	-2.7
14	4.0	-23.1	46	16.8	-2.2
15	4.4	-22.2	47	17.2	-1.8
16	4.8	-21.4	48	17.6	-1.4
17	5.2	-20.6	49	18.0	-1.0
18	5.6	-19.8	50	18.4	-0.6
19	6.0	-19.0	51	18.8	-0.2
20	6.4	-18.2	52	19.2	0.2
21	6.8	-17.4	53	19.6	0.6
22	7.2	-16.6	54	20.0	0.9
23	7.6	-15.9	55	20.4	1.2
24	8.0	-15.2	56	20.8	1.5
25	8.4	-14.5	57	21.2	1.8
26	8.8	-13.8	58	21.6	2.1
27	9.2	-13.1	59	22.0	2.4
28	9.6	-12.4	60	22.4	2.7
29	10.0	-11.7	61	22.8	2.9
30	10.4	-11.0	62	23.2	3.1
31	10.8	-10.4	63	23.6	3.3
32	11.2	-9.8	64	24.0	3.5





Application Information

Mute Operation

The MUTE pin is an input for controlling the output state of the PAM8007. A logic low on this pin disables the outputs, and a logic high on this pin enables the outputs. This pin may be used as a quick disable or enable of the outputs without a volume fade. Quiescent current is listed in the electrical characteristics table. The MUTE pin can be left floating due to the internal pull-up.

For the best power on/off pop performance, the amplifier should be placed in the MUTE mode prior to turning on/off the power supply.

Shutdown Operation

In order to reduce power consumption while not in use, the PAM8007 contains shutdown circuitry to turn off the amplifier's bias circuitry. The amplifier is turned off when logic low is placed on the SHDN pin. By switching the SHDN pin connected to GND, the PAM8007 supply current draw will be minimized in idle mode. The SHDN pin can be left floating due to the internal pull-up.

Line/Ear Operation

In order to control the speaker/headphone switch, the PAM8007 contains detect circuitry. When line/ear logic low, speaker actice; when logic high, earphone active.

Power Supply Decoupling

The PAM8007 is a high performance CMOS audio amplifier that requires an adequate power supply decoupling to ensure the output THD and PSRR are as low as possile. Power supply decoupling affects low frequency on the power supply leads for higher frey response. Optimum decoupling is achieved by using two capacitors of different types that target different types of noise frequency transients, spike, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 1.0μ F, placed as close as possible to the device V_{DD} terminal works best. For filtering lower-frequency noise signals, a large capacitor of 10μ F (ceramic) or greater placed near the audio power amplifier is recommended.

Input Capacitor (C_I)

Large input capacitors are both expensive and space hungry for portable designs. Clearly, a certai sized capacitor is needed to couple in low frequencies without severe attenuation. But in many cases the speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 100Hz to 150Hz. Thus, using a large input capacitor may not increase actual system performance. In this case, inout capacitor (C_1) and input resistance (R_1) of the amplifier form a high-pass filter with the corner frequency determined equation below;

$$f_{\rm C} = \frac{1}{2\Pi R_{\rm I} C_{\rm I}}$$

In addition to system cost and size, click and pop performance is affected by the size of the input coupling capacitor, C_l . A larger inout coupling capacitor requires more charge to reach its quiescent DC voltage (nominally $\frac{1}{2} V_{DD}$). This charge comes from the internal circuit via the feedback and is apt to create pops upon device enable. Thus, by minmizing the capacitor size based on necessary low frequency response, turn-on pops can be minimized.

Analog Reference Bypass Capacitor (CBYP)

Analog Reference Bypass Capacitior (C_{BYP}) is the most critical capacitor and serves several important functions. During start-up or recovery from shutdown mode, C_{BYP} determines the rate at which the amplifier starts up. The second function is to reduce noise produced by the power supply caused by coupling into the output device signal. The noise is from the internal analog reference to the amplifier, which appears as degraded PSRR and THD+N.

A ceramic bypass capacitor (C_{BYP}) of 0.47μ F to 1.0μ F is recommended for the best THD and noise performance. Increasing the bypass capacitor reduces clicking and popping noise from power on/off and entering and leaving shutdown.

Short Circuit Protection (SCP)

The PAM8007 has short circuit protection circuitry on the outputs that prevents the device from damage when output-to-output and output-to GND short. When a short circuit is detected on the outputs, the outputs are disabled immediately. If the short was removed, the device activates again.





Application Information (cont.)

Over Temperature Protection

Thermal protection on the PAM8007 prevents the device from damage when the internal die temperature exceeds +150°C. There is a 15 degree tolerance on this trip point from device to device. Once the die temperature exceeds the thermal set point, the device outputs are disabled. This is not a latched fault. The thermal fault is cleared once the temperature of the die is reduced by +30°C. This large hysteresis will prevent motor boating sound well. The device begins normal operation at this point without external system interaction.

How to Reduce EMI (Elect ro Magnetic Interference)

A simple solution is to put an additional capacitor 1000µF at power supply terminal for power line coupling if the traces from amplifier to speakers are short (<20CM).

Most applications require a ferrite bead filter as shown at Figure 1. The ferrite filter reduces EMI around 1MHz and higher. When selecting a ferrite bead, choose one with high impedance at high frequencies, and low impedance at low frequencies (MH2012HM221-T).

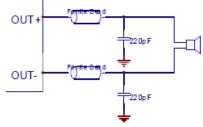


Figure 1. Ferrite Bead Filter to Reduce EMI

PCB Layout Guidelines Grounding

At this stage it is paramount to notice the necessity of separate grounds. Noise currents in the output power stage need to be returned to output noise ground and nowhere else. Were these currents to circulate elsewhere, they may get into the power supply, the signal ground, etc, worse yet, they may form a loop and radiate noise. Any of these cases results in degraded amplifier performance. The logical returns for the output noise currents associated with Class D switching are the respective PGND pins for each channel. The switch state diagram illustrates that PGND is instrumental in nearly every switch state. This is the perfect point to which the output noise ground trace should return. Also note that output noise ground is channel specific. A two channel amplifier has two seperate channels and consequently must have two seperate output noise ground traces. The layout of the PAM8007 offers separate PGND connections for each channel and in some cases each side of the bridge. Output noise grounds must be tied to system ground at the power in exclusively. Signal currents for the inputs, reference, etc need to be returned to quite ground. This ground is only tied to the signal components and the GND pin, and GND then tied to system ground.

PCB Layout Example

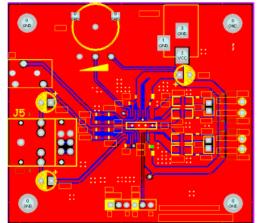


Figure 2. Top Layer

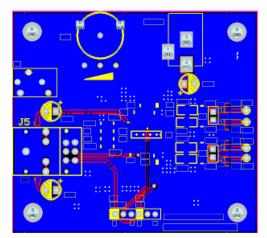


Figure 3. Bottom Layer



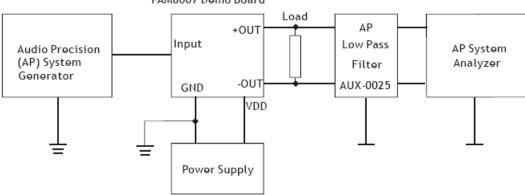


Application Information (cont.)

Test Setup for Performance Testing (Class D)

1. When the PAM8007 works with LC filters, it should be connected with the speaker before it's powered on, otherwise it will be damaged easily.

- 2. When the PAM8007 works without LC filters, it's better to add a ferrite chip bead at the outgoing line of speaker for suppressing the possible electromagnetic interference.
- 3. The absolute maximum rating of the PAM8007 operation voltage is 6.0V. When the PAM8007 is powered with four battery cells, it should be noted that the voltage of four new dry or alkaline batteries is over 6V, higher than its maximum operation voltage, which probably make the device damaged. Therefore, it's recommended to use either four Ni-MH (Nickel Metal Hydride) rechargeable batteries or three dry or alkaline batteries.
- 4. The input signal should not be too high, if too high, it will cause the clipping of output signal when increasing the volume. Because the DC volume control of the PAM8007 has big gain, it will make the device damaged.
- 5. When testing the PAM8007 without LC filters by using resistor instead of speaker as the output load, the test results, e.g. THD or efficiency, will be worse than those using speaker as load.



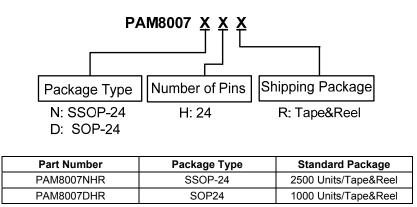
PAM8007 Demo Board

Notes: 1. The Audio Precision (AP) AUX-0025 low pass filter is necessary for class-D amplifier measurement with AP analyzer. 2. Two 22µH inductors are used in series with load resistor to emulate the small speaker for efficiency measurement.

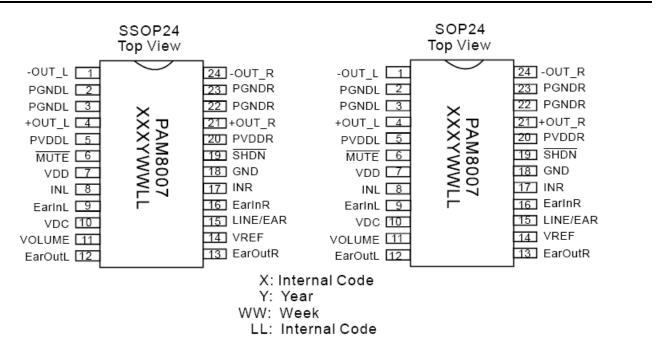




Ordering Information



Marking Information

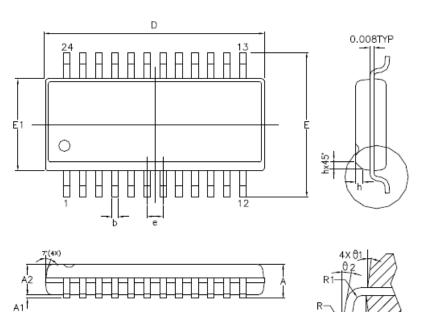






Package Outline Dimensions (All dimensions in mm.)

SSOP-24



9

4X θ1

L1

SYMBOLS	MIN.	NOM.	MAX.
A	0.053	0.061	0.069
A1	0.004	-	0.010
A2	0.049	0.057	0.065
b	0.008	0.010	0.012
D	0.335	0.341	0.347
E	0,228	0,236	0.244
E1	0.150	0.154	0.158
e	-	0.025	-
L	0.016	0.033	0.050
L1		0.041 R	EF
R	0.003	-	-
R1	0.003	-	-
h	0,010	0,015	0,020
θ	0,	4'	8'
θ1	5'	10	15'
θ2	0,	-	-

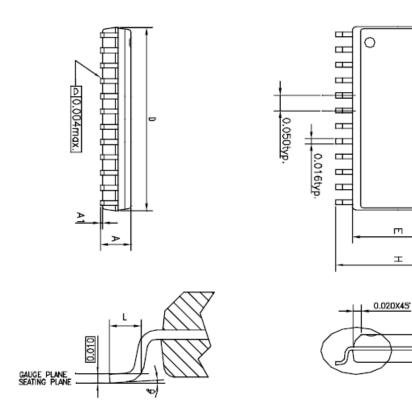
UNIT : INCH





Package Outline Dimensions (cont.) (All dimensions in mm.)

SOP-24



SYMBOLS	MIN.	NOM	MAX.
A	0.093	0.099	0.104
A1	0.004	-	0.012
D	0.599	0.600	0.614
E	0.291	0.295	0.299
Н	0.394	0.406	0.419
L	0.016	0.035	0.050
6°	0	-	8

UNIT : INCH

NOTES:

- 1.JEDEC OUTLINE : MS-013 AD
- 2.DIMENSIONS "D" DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.MOLD FLASH, PROTRUSIONS AND CATE BURRS SHALL NOT EXCEED .15mm (.006in) PER SIDE.
- 3.0IMENSIONS "E" DOES NOT INCLUDE INTER-LEAD FLASH, OR PROTRUSIONS. INTER-LEAD FLASH AND PROTRUSIONS SHALL NOT EXCEED .25mm (.010in) PER SIDE.





IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

- 1. are intended to implant into the body, or
- 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2012, Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))